

=> d L2 ibib abs 1-3

L2 ANSWER 1 OF 1 CAPLUS COPYRIGHT 2007 ACS on STN
ACCESSION NUMBER: 2005:546990 CAPLUS
DOCUMENT NUMBER: 143:62744
TITLE: Process for making high voltage laminar cathode
materials for lithium rechargeable batteries
INVENTOR(S): Howard, Wilmont Frederick; Sheargold, Stephen Wilfred;
Thurston, Anthony Michael; Towa, Felix Mbanga
PATENT ASSIGNEE(S): USA
SOURCE: U.S. Pat. Appl. Publ., 8 pp.
CODEN: USXXCO
DOCUMENT TYPE: Patent
LANGUAGE: English
FAMILY ACC. NUM. COUNT: 1
PATENT INFORMATION:

PATENT NO.	KIND	DATE	APPLICATION NO.	DATE
US 2005136329	A1	20050623	US 2003-743077	20031223
AU 2004313086	A1	20050721	AU 2004-313086	20041116
CA 2551562	A1	20050721	CA 2004-2551562	20041116
WO 2005067077	A2	20050721	WO 2004-US38073	20041116
WO 2005067077	A3	20060511		
W:	AE, AG, AL, AM, AT, AU, AZ, BA, BB, BG, BR, BW, BY, BZ, CA, CH, CN, CO, CR, CU, CZ, DE, DK, DM, DZ, EC, EE, EG, ES, FI, GB, GD, GE, GH, GM, HR, HU, ID, IL, IN, IS, JP, KE, KG, KP, KR, KZ, LC, LK, LR, LS, LT, LU, LV, MA, MD, MG, MK, MN, MW, MX, MZ, NA, NI, NO, NZ, OM, PG, PH, PL, PT, RO, RU, SC, SD, SE, SG, SK, SL, SY, TJ, TM, TN, TR, TT, TZ, UA, UG, UZ, VC, VN, YU, ZA, ZM, ZW			
RW:	BW, GH, GM, KE, LS, MW, MZ, NA, SD, SL, SZ, TZ, UG, ZM, ZW, AM, AZ, BY, KG, KZ, MD, RU, TJ, TM, AT, BE, BG, CH, CY, CZ, DE, DK, EE, ES, FI, FR, GB, GR, HU, IE, IS, IT, LU, MC, NL, PL, PT, RO, SE, SI, SK, TR, BF, BJ, CF, CG, CI, CM, GA, GN, GQ, GW, ML, MR, NE, SN, TD, TG			
EP 1698007	A2	20060906	EP 2004-821039	20041116
R:	AT, BE, CH, DE, DK, ES, FR, GB, GR, IT, LI, LU, NL, SE, MC, PT, IE, SI, LT, LV, FI, RO, MK, CY, AL, TR, BG, CZ, EE, HU, PL, SK, HR, IS, YU			
CN 1898824	A	20070117	CN 2004-80038789	20041116
PRIORITY APPLN. INFO.:			US 2003-743077	A 20031223
			WO 2004-US38073	W 20041116
AB	Intercalation cathode materials especially suited for use in high-voltage, high-energy lithium rechargeable batteries, have the formulas $\text{Li}[\text{Li}(1-2x)/3\text{Mn}(2-x)/3\text{Ni}(x-y)\text{O}_2]$, where $0 < x < 0.5$, $0 < y \leq 0.25$, $x > y$, and M is one or more divalent cations from Ca, Cu, Mg, and Zn. A process for making such materials is also provided.			

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(FILE 'HOME' ENTERED AT 10:38:43 ON 06 APR 2007)

FILE 'REGISTRY' ENTERED AT 10:43:54 ON 06 APR 2007

L1 3 S (1.01-1.35)/LI AND (0.01-0.15)/CU AND (0.5-0.7)/MN AND (0.01-

FILE 'CAPLUS' ENTERED AT 10:45:49 ON 06 APR 2007

L2 1 S L1

=> d L6 ibib abs 1-3

L6 ANSWER 1 OF 1 CAPLUS COPYRIGHT 2007 ACS on STN
ACCESSION NUMBER: 2005:546990 CAPLUS
DOCUMENT NUMBER: 143:62744
TITLE: Process for making high voltage laminar cathode materials for lithium rechargeable batteries
INVENTOR(S): Howard, Wilmont Frederick; Sheargold, Stephen Wilfred; Thurston, Anthony Michael; Towa, Felix Mbanga
PATENT ASSIGNEE(S): USA
SOURCE: U.S. Pat. Appl. Publ., 8 pp.
CODEN: USXXCO
DOCUMENT TYPE: Patent
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FAMILY ACC. NUM. COUNT: 1
PATENT INFORMATION:

PATENT NO.	KIND	DATE	APPLICATION NO.	DATE
US 2005136329	A1	20050623	US 2003-743077	20031223
AU 2004313086	A1	20050721	AU 2004-313086	20041116
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WO 2005067077	A3	20060511		
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RW:	BW, GH, GM, KE, LS, MW, MZ, NA, SD, SL, SZ, TZ, UG, ZM, ZW, AM, AZ, BY, KG, KZ, MD, RU, TJ, TM, AT, BE, BG, CH, CY, CZ, DE, DK, EE, ES, FI, FR, GB, GR, HU, IE, IS, IT, LU, MC, NL, PL, PT, RO, SE, SI, SK, TR, BF, BJ, CF, CG, CI, CM, GA, GN, GQ, GW, ML, MR, NE, SN, TD, TG			
EP 1698007	A2	20060906	EP 2004-821039	20041116
R:	AT, BE, CH, DE, DK, ES, FR, GB, GR, IT, LI, LU, NL, SE, MC, PT, IE, SI, LT, LV, FI, RO, MK, CY, AL, TR, BG, CZ, EE, HU, PL, SK, HR, IS, YU			
CN 1898824	A	20070117	CN 2004-80038789	20041116
PRIORITY APPLN. INFO.:			US 2003-743077	A 20031223
			WO 2004-US38073	W 20041116

AB Intercalation cathode materials especially suited for use in high-voltage, high-energy lithium rechargeable batteries, have the formulas $\text{Li}[\text{Li}(1-2x)/3\text{MyMn}(2-x)/3\text{Ni}(x-y)\text{O}_2]$, where $0 < x < 0.5$, $0 < y \leq 0.25$, $x > y$, and M is one or more divalent cations from Ca, Cu, Mg, and Zn. A process for making such materials is also provided.

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L76 NOT FOUND

The L-number entered has not been defined in this session, or it has been deleted. To see the L-numbers currently defined in this session, enter DISPLAY HISTORY at an arrow prompt (=>).

=> d L7 ibib abs 1-4

L7 ANSWER 1 OF 4 CAPLUS COPYRIGHT 2007 ACS on STN
ACCESSION NUMBER: 2006:402355 CAPLUS
DOCUMENT NUMBER: 144:415971
TITLE: Method of preparation of conductive agent-cathode active material composite for lithium secondary battery
INVENTOR(S): Cheon, Sang-Eun; Yoo, Seok-Yoon; Yoon, Hye-Won; Kim,

PATENT ASSIGNEE(S): Jae-Kyung Samsung Sdi Co., Ltd., S. Korea
 SOURCE: Eur. Pat. Appl., 27 pp.
 CODEN: EPXXDW
 DOCUMENT TYPE: Patent
 LANGUAGE: English
 FAMILY ACC. NUM. COUNT: 1
 PATENT INFORMATION:

PATENT NO.	KIND	DATE	APPLICATION NO.	DATE
EP 1653534	A1	20060503	EP 2005-110064	20051027
R: AT, BE, CH, DE, DK, ES, FR, GB, GR, IT, LI, LU, NL, SE, MC, PT, IE, SI, LT, LV, FI, RO, MK, CY, AL, TR, BG, CZ, EE, HU, PL, SK, BA, HR, IS, YU				
KR 2006037618	A	20060503	KR 2004-86630	20041028
US 2006093920	A1	20060504	US 2005-258731	20051025
CN 1770516	A	20060510	CN 2005-10116672	20051026
JP 2006128119	A	20060518	JP 2005-314501	20051028

PRIORITY APPLN. INFO.: KR 2004-86630 A 20041028

AB The invention relates to a conductive agent/pos. active material composite for a lithium secondary battery. The composite includes a pos. active material capable of reversibly intercalating/deintercalating lithium ions, and a conductive agent on the surface of the pos. active material. The conductive agent comprises a first conductive agent having a sp. surface area ranging from about 200 to about 1500 m²/g and a second conductive agent having a sp. surface area of about 100 m²/g or less.

REFERENCE COUNT: 16 THERE ARE 16 CITED REFERENCES AVAILABLE FOR THIS RECORD. ALL CITATIONS AVAILABLE IN THE RE FORMAT

L7 ANSWER 2 OF 4 CAPLUS COPYRIGHT 2007 ACS on STN

ACCESSION NUMBER: 2005:546990 CAPLUS

DOCUMENT NUMBER: 143:62744

TITLE: Process for making high voltage laminar cathode materials for lithium rechargeable batteries

INVENTOR(S): Howard, Wilmont Frederick; Sheargold, Stephen Wilfred; Thurston, Anthony Michael; Towa, Felix Mbanga

PATENT ASSIGNEE(S): USA

SOURCE: U.S. Pat. Appl. Publ., 8 pp.

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DOCUMENT TYPE: Patent

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FAMILY ACC. NUM. COUNT: 1

PATENT INFORMATION:

PATENT NO.	KIND	DATE	APPLICATION NO.	DATE
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AU 2004313086	A1	20050721	AU 2004-313086	20041116
CA 2551562	A1	20050721	CA 2004-2551562	20041116
WO 2005067077	A2	20050721	WO 2004-US38073	20041116
WO 2005067077	A3	20060511		

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 RW: BW, GH, GM, KE, LS, MW, MZ, NA, SD, SL, SZ, TZ, UG, ZM, ZW, AM, AZ, BY, KG, KZ, MD, RU, TJ, TM, AT, BE, BG, CH, CY, CZ, DE, DK, EE, ES, FI, FR, GB, GR, HU, IE, IS, IT, LU, MC, NL, PL, PT, RO, SE, SI, SK, TR, BF, BJ, CF, CG, CI, CM, GA, GN, GQ, GW, ML, MR, NE, SN, TD, TG

EP 1698007	A2	20060906	EP 2004-821039	20041116
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IE, SI, LT, LV, FI, RO, MK, CY, AL, TR, BG, CZ, EE, HU, PL, SK,
HR, IS, YU

CN 1898824 A 20070117 CN 2004-80038789 20041116
PRIORITY APPLN. INFO.: US 2003-743077 A 20031223
WO 2004-US38073 W 20041116

AB Intercalation cathode materials especially suited for use in high-voltage, high-energy lithium rechargeable batteries, have the formulas $\text{Li}[\text{Li}(1-2x)/3\text{MgMn}(2-x)/3\text{Ni}(x-y)\text{O}_2]$, where $0 < x < 0.5$, $0 < y \leq 0.25$, $x > y$, and M is one or more divalent cations from Ca, Cu, Mg, and Zn. A process for making such materials is also provided.

L7 ANSWER 3 OF 4 CAPLUS COPYRIGHT 2007 ACS on STN

ACCESSION NUMBER: 2003:96387 CAPLUS
DOCUMENT NUMBER: 138:356159
TITLE: Electrochemical performance of layered $\text{Li}[\text{Li}_{0.15}\text{Ni}_{0.275}\text{xMgMn}_{0.575}]\text{O}_2$ cathode materials for lithium secondary batteries
AUTHOR(S): Sun, Y.-K.; Kim, M. G.; Kang, S.-H.; Amine, K.
CORPORATE SOURCE: Department of Chemical Engineering, Hanyang University, Seoul 133-791, S. Korea
SOURCE: Journal of Materials Chemistry (2003), 13(2), 319-322
CODEN: JMACEP; ISSN: 0959-9428
PUBLISHER: Royal Society of Chemistry
DOCUMENT TYPE: Journal
LANGUAGE: English

AB The $\text{Li}[\text{Li}_{0.15}\text{Ni}_{0.275}\text{xMgMn}_{0.575}]\text{O}_2$ ($x = 0, 0.02$, and 0.04) powders were synthesized using a sol-gel method. The layered structure of the materials is stabilized by a small amount of Mg substitution for Ni. The structural stability and cycling behavior are improved by an increase in the Mg content. XAS measurements showed that charge compensation by delithiation could be achieved by the oxidation of the oxygen ion as well as by the oxidation of Ni^{2+} to Ni^{3+} , while maintaining the Mn atoms in the 4+ oxidation state.

REFERENCE COUNT: 19 THERE ARE 19 CITED REFERENCES AVAILABLE FOR THIS RECORD. ALL CITATIONS AVAILABLE IN THE RE FORMAT

L7 ANSWER 4 OF 4 CAPLUS COPYRIGHT 2007 ACS on STN

ACCESSION NUMBER: 1998:596036 CAPLUS
DOCUMENT NUMBER: 129:205207
TITLE: Secondary lithium batteries with lithium and magnesium containing oxide cathodes
INVENTOR(S): Igawa, Akiko; Tsuruoka, Shigeo; Yoshikawa, Masanori; Muranaka, Kiyoshi; Komatsu, Yoshimi; Yamauchi, Shuko
PATENT ASSIGNEE(S): Hitachi, Ltd., Japan
SOURCE: Jpn. Kokai Tokkyo Koho, 25 pp.
CODEN: JKXXAF
DOCUMENT TYPE: Patent
LANGUAGE: Japanese
FAMILY ACC. NUM. COUNT: 1
PATENT INFORMATION:

PATENT NO.	KIND	DATE	APPLICATION NO.	DATE
JP 10241691	A	19980911	JP 1997-354358	19971224
JP 3624663	B2	20050302		

PRIORITY APPLN. INFO.: JP 1996-343041 A 19961224

AB The batteries use cathodes composed layer structured LiMO_2 , where M = Mn, Co, Ni, and/or Fe, and part of Li is replaced by Mg. The cathode active mass is preferably $\text{Li}_w\text{Mg}_v\text{Ni}_x\text{M}_1\text{yNzO}_2$, where $\text{M}_1 = \text{Mn, Co, and/or Fe}$, $\text{N} = \text{Si, Al, Ca, Cu, P, In, Sn, Mo, Nb, Y, Bi and/or B}$, $0 \leq w \leq 1.2$, $0.001 \leq v \leq 0.02$, $0.5 \leq x < 0.85$, $0.05 \leq y \leq 0.5$, and $0 \leq z \leq 0.2$; $\text{Li}_w\text{Mg}_v\text{Co}_x\text{M}_2\text{z}'\text{O}_2$, where $\text{M}_2 = \text{Ni, Mn, Fe, Si, Al, Ca, Cu, P, In, Sn, Mo, Nb, YH, Bi and/or B}$, and 0

$z \leq 0.5$; LiwMgvMnxM3z'O2, where M3 = Ni, Co, Fe, Si, Al, Ca, Cu, P, In, Sn, Mo, Nb, Y, Bi and/or B; or LiwMgvFex M4z'O2, where M4 = Ni, Co, Mn, Si, Al, Ca, Cu, P, In, Sn, Mo, Nb, Y, Bi and/or B.

=> d L8 ibib abs 1-4

L8 ANSWER 1 OF 1 CAPLUS COPYRIGHT 2007 ACS on STN

ACCESSION NUMBER: 2005:546990 CAPLUS

DOCUMENT NUMBER: 143:62744

TITLE: Process for making high voltage laminar cathode materials for lithium rechargeable batteries

INVENTOR(S): Howard, Wilmont Frederick; Sheargold, Stephen Wilfred; Thurston, Anthony Michael; Towa, Felix Mbanga

PATENT ASSIGNEE(S): USA

SOURCE: U.S. Pat. Appl. Publ., 8 pp.

CODEN: USXXCO

DOCUMENT TYPE: Patent

LANGUAGE: English

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WO 2005067077	A2	20050721	WO 2004-US38073	20041116
WO 2005067077	A3	20060511		

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RW: BW, GH, GM, KE, LS, MW, MZ, NA, SD, SL, SZ, TZ, UG, ZM, ZW, AM, AZ, BY, KG, KZ, MD, RU, TJ, TM, AT, BE, BG, CH, CY, CZ, DE, DK, EE, ES, FI, FR, GB, GR, HU, IE, IS, IT, LU, MC, NL, PL, PT, RO, SE, SI, SK, TR, BF, BJ, CF, CG, CI, CM, GA, GN, GQ, GW, ML, MR, NE, SN, TD, TG

EP 1698007	A2	20060906	EP 2004-821039	20041116
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CN 1898824	A	20070117	CN 2004-80038789	20041116
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PRIORITY APPLN. INFO.:	US 2003-743077	A	20031223
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WO 2004-US38073	W	20041116
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AB Intercalation cathode materials especially suited for use in high-voltage, high-energy lithium rechargeable batteries, have the formulas $\text{Li}[\text{Li}(1-2x)/3\text{Mn}(2-x)/3\text{Ni}(x-y)\text{O}_2]$, where $0 < x < 0.5$, $0 < y \leq 0.25$, $x > y$, and M is one or more divalent cations from Ca, Cu, Mg, and Zn. A process for making such materials is also provided.

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'HIDT' IS NOT A VALID FORMAT FOR FILE 'CAPLUS'

The following are valid formats:

ABS ----- GI and AB

ALL ----- BIB, AB, IND, RE

APPS ----- AI, PRAI

BIB ----- AN, plus Bibliographic Data and PI table (default)

CAN ----- List of CA abstract numbers without answer numbers
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 CLASS ----- IPC, NCL, ECLA, FTERM
 DALL ----- ALL, delimited (end of each field identified)
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 MAX ----- ALL, plus Patent FAM, RE
 PATS ----- PI, SO
 SAM ----- CC, SX, TI, ST, IT
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 SCAN must be entered on the same line as the DISPLAY,
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 STD ----- BIB, CLASS

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 IMAX ----- MAX, indented with text labels
 ISTD ----- STD, indented with text labels

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 SIBIB ----- IBIB, no citations

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 containing hit terms
 HITRN ----- HIT RN and its text modification
 HITSTR ----- HIT RN, its text modification, its CA index name, and
 its structure diagram
 HITSEQ ----- HIT RN, its text modification, its CA index name, its
 structure diagram, plus NTE and SEQ fields
 FHITSTR ----- First HIT RN, its text modification, its CA index name, and
 its structure diagram
 FHITSEQ ----- First HIT RN, its text modification, its CA index name, its
 structure diagram, plus NTE and SEQ fields
 KWIC ----- Hit term plus 20 words on either side
 OCC ----- Number of occurrence of hit term and field in which it occurs

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ABS ----- GI and AB
 ALL ----- BIB, AB, IND, RE
 APPS ----- AI, PRAI
 BIB ----- AN, plus Bibliographic Data and PI table (default)
 CAN ----- List of CA abstract numbers without answer numbers

CBIB ----- AN, plus Compressed Bibliographic Data
 CLASS ----- IPC, NCL, ECLA, FTERM
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 DMAX ----- MAX, delimited for post-processing
 FAM ----- AN, PI and PRAI in table, plus Patent Family data
 FBIB ----- AN, BIB, plus Patent FAM
 IND ----- Indexing data
 IPC ----- International Patent Classifications
 MAX ----- ALL, plus Patent FAM, RE
 PATS ----- PI, SO
 SAM ----- CC, SX, TI, ST, IT
 SCAN ----- CC, SX, TI, ST, IT (random display, no answer numbers;
 SCAN must be entered on the same line as the DISPLAY,
 e.g., D SCAN or DISPLAY SCAN)
 STD ----- BIB, CLASS

 IABS ----- ABS, indented with text labels
 IALL ----- ALL, indented with text labels
 IBIB ----- BIB, indented with text labels
 IMAX ----- MAX, indented with text labels
 ISTD ----- STD, indented with text labels

 OBIB ----- AN, plus Bibliographic Data (original)
 OIBIB ----- OBIB, indented with text labels

 SBIB ----- BIB, no citations
 SIBIB ----- IBIB, no citations

 HIT ----- Fields containing hit terms
 HITIND ----- IC, ICA, ICI, NCL, CC and index field (ST and IT)
 containing hit terms
 HITRN ----- HIT RN and its text modification
 HITSTR ----- HIT RN, its text modification, its CA index name, and
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 HITSEQ ----- HIT RN, its text modification, its CA index name, its
 structure diagram, plus NTE and SEQ fields
 FHITSTR ----- First HIT RN, its text modification, its CA index name, and
 its structure diagram
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 structure diagram, plus NTE and SEQ fields
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 ENTER DISPLAY FORMAT (BIB):end

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L2 1 S L1

FILE 'REGISTRY' ENTERED AT 10:48:44 ON 06 APR 2007

L3 1 S (1.01-1.35)/LI AND (0.01-0.15)/CA AND (0.5-0.7)/MN AND (0.01-
L4 14 S (1.01-1.35)/LI AND (0.01-0.15)/MG AND (0.5-0.7)/MN AND (0.01-
L5 1 S (1.01-1.35)/LI AND (0.01-0.15)/ZN AND (0.5-0.7)/MN AND (0.01-

FILE 'CAPLUS' ENTERED AT 10:49:42 ON 06 APR 2007

L6 1 S L3
L7 4 S L4
L8 1 S L5